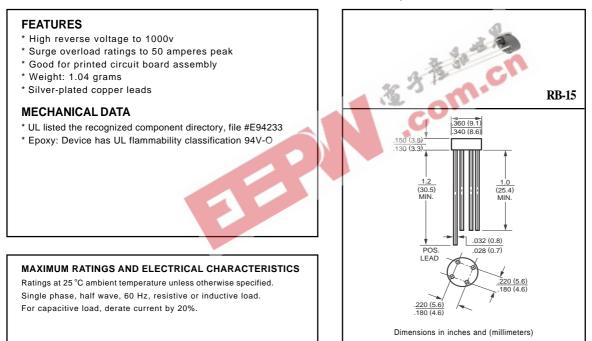


SINGLE-PHASE GLASS PASSIVATED SILICON BRIDGE RECTIFIER

VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.5 Amperes

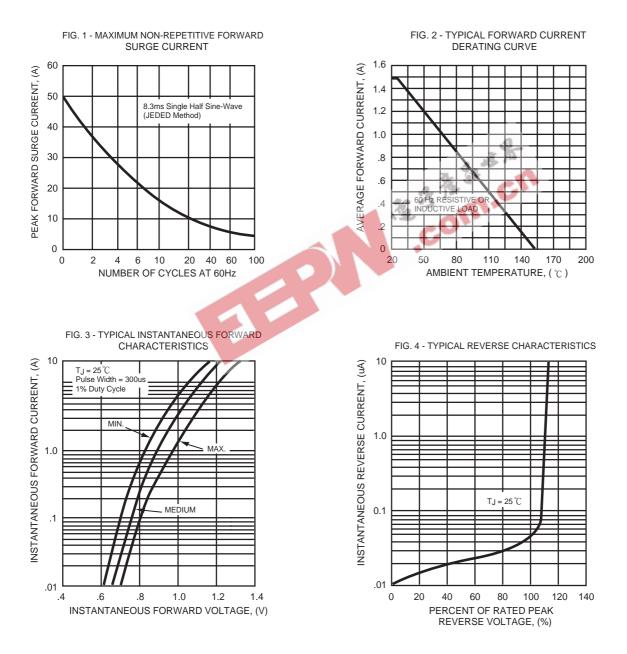


MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	RB151	RB152	RB153	RB154	RB155	RB156	RB157	UNITS
Maximum Recurrent Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage	Vrms	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output Current at TA = 25°C	lo	1.5							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave	IFSM 50						Amps		
superimposed on rated load (JEDEC method)	II OM								
Typical Thermal Resistance (Note 1)	RθJA	36							°C/W
	RθJC	12							
Operating Temperature Range	TJ	-55 to + 150							٥C
Storage Temperature Range	Tstg	-55 to + 150						٥C	

ELECTRICAL CHARACTERISTICS (At TA = $25^{\circ}C$ unless otherwise noted)

CHARACTERISTICS		SYMBOL	RB151	RB152	RB153	RB154	RB155	RB156	RB157	UNITS
Maximum Forward Voltage Drop per Bridge Element at 1.0A DC		Vf	1.0							Volts
Maximum Reverse Current at Rated	@TA = 25°C	1-	5.0							uAmps
DC Blocking Voltage per element	@TA = 100°C	lr	1							
NOTE:1.Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length P.C.B. mounting.								2005-3		
2. "Fully ROHS compliant", "100% Sn plating (Pb-free)".								REV: A		



RATING AND CHARACTERISTIC CURVES (RB151 THRU RB157)

RECTRON-